WNSC2D30650W



Silicon Carbide Diode Rev.01 - 27 January 2022

Product data sheet

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1. General description

Silicon Carbide Schottky diode in a 2-lead TO247-2L plastic package, designed for high frequency switched-mode power supplies.

2. Features and benefits

- Highly stable switching performance
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- High Forward Surge Capability I_{FSM}
- · Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

<u> </u>			Values				
Symbol	Parameter	Conditions	Values		Unit		
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			6	50		V
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 102 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		30		A	
T _j	junction temperature			175		°C	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 30 A; T _j = 25 °C; <u>Fig. 5</u>		-	1.45	1.7	V
		I _F = 30 A; T _j = 150 °C; <u>Fig. 5</u>		-	1.75	2.1	V
Dynamic	characteristics						
Q _r	recovered charge	I _F = 30 A; dI _F /dt = 500 A/μs; V _R = 400 V; T _i = 25 °C; <u>Fig. 7</u>		-	48	-	nC

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		
2	А	anode		K — A 001aaa020
mb	mb	mounting base; connected to cathode	Г. Г	

6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
WNSC2D30650W	TO247-2L	WNSC2D30650WQ	Tube	30	TO247L-2L	10-Nov-2020		

7. Marking

Table 4. Marking codes						
Type number	Marking codes					
WNSC2D30650W	WNSC2D 30650W					

2alk15-002

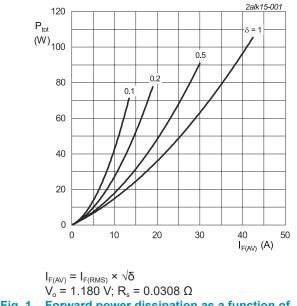
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		650	V
V _{RWM}	crest working reverse voltage		650	V
V _R	reverse voltage	DC	650	V
$I_{F(AV)}$	average forward current	δ = 0.5; square-wave pulse; T _{mb} ≤ 102 °C; Fig. 1; Fig. 2; Fig. 3	30	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 μs; T _{mb} ≤ 102 °C; square-wave pulse	30	A
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	155	А
	forward current	t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse	1200	А
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; t_p = 10 ms	120	A ² s
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C

250



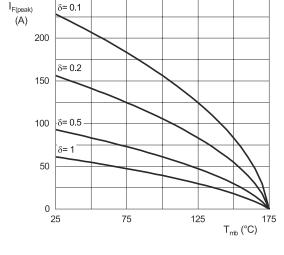
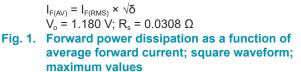


Fig. 2. Current derating as a function of mounting base temperature



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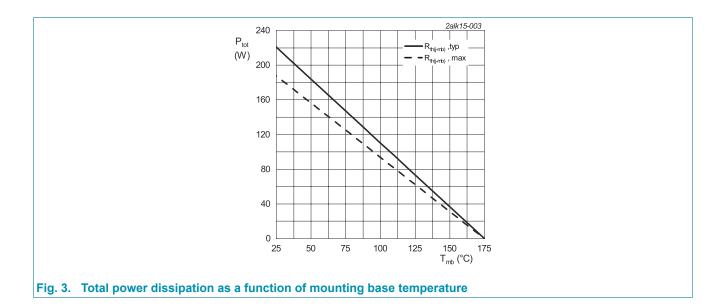
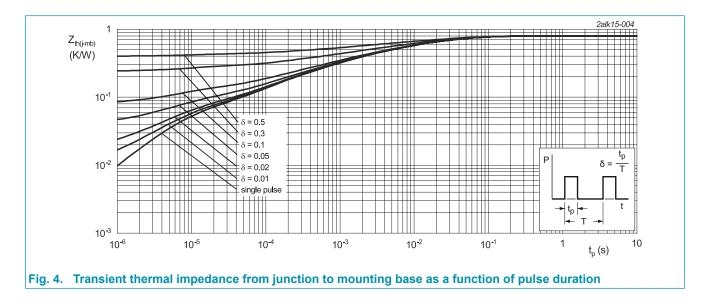


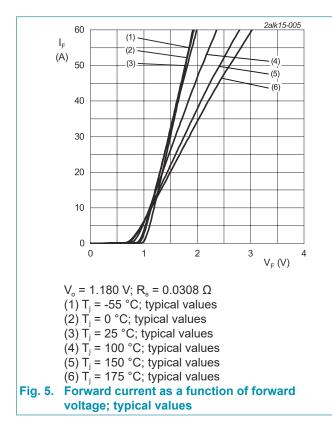
Table 6. Thermal characteristics							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	Fig. 4		-	0.68	0.8	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air		-	40	-	K/W

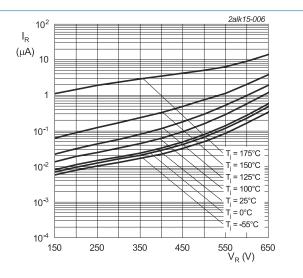
9. Thermal characteristics



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
V _F	forward current	I _F = 30 A; T _j = 25 °C; <u>Fig. 5</u>	-	1.45	1.7	V
		I _F = 30 A; T _j = 150 °C; <u>Fig. 5</u>	-	1.75	2.1	V
		I _F = 30 A; T _j = 175 °C; <u>Fig. 5</u>	-	1.85	2.4	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C; <u>Fig. 6</u>	-	5	100	μA
		V _R = 650 V; T _j = 175 °C; <u>Fig. 6</u>	-	35	200	μA
Dynamic	characteristics					
Q _r	recovered charge	$I_F = 30 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 500 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	48	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	980	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C	-	105	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C	-	100	-	pF
E _{as}	non-repetitive avalanche energy	I _R = 6.3 A; L = 5 mH; T _{j(init)} = 25 °C	99	-	-	mJ



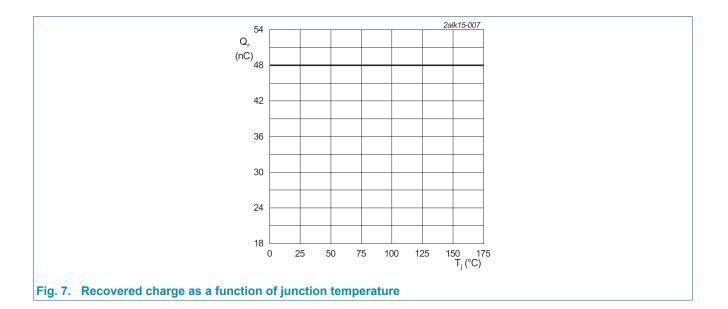




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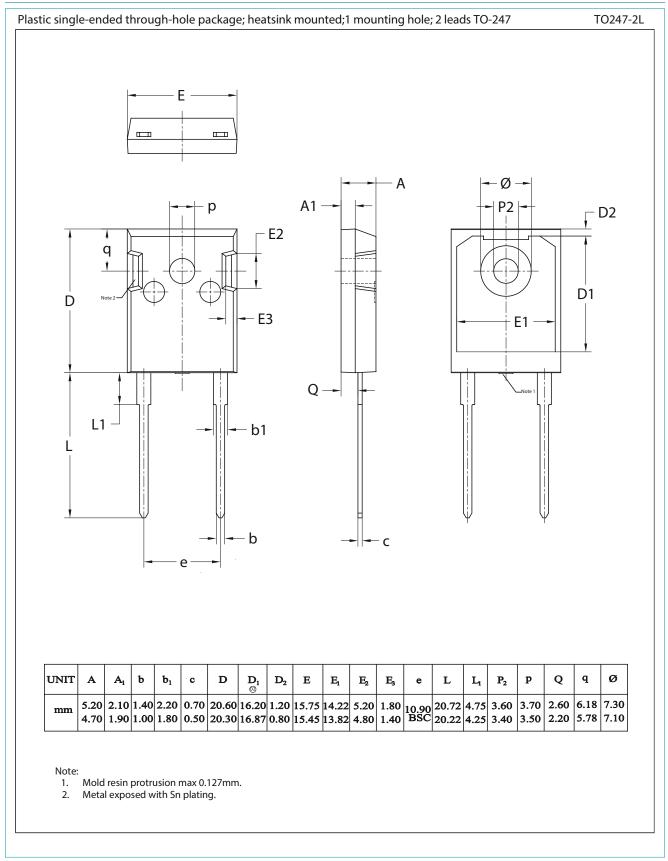
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Silicon Carbide Diode



WNSC2D30650W Silicon Carbide Diode

11. Package outline



WNSC2D30650W
Product data sheet

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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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